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Low voltage PNP transistor

Features

- TO-92 package suitable for through-hole PCB assembly

Application

- Voltage regulation
- Relay driver
- Generic switch

Description

The STX826 is a low voltage PNP transistor manufactured in planar technology with base island layout.

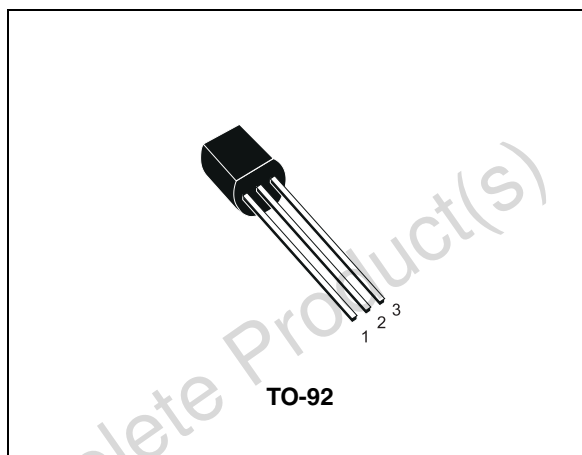


Figure 1. Internal schematic diagram

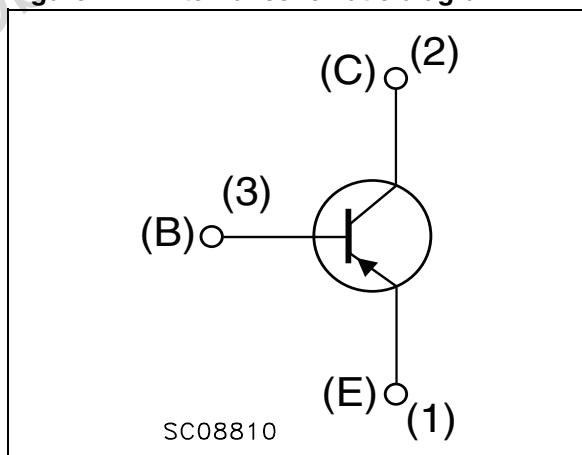


Table 1. Device summary

Order code	Marking	Package	Packaging
STX826	X826	TO-92	Bag

1 Electrical ratings

Table 2. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V_{CBO}	Collector-base voltage ($I_E = 0$)	-60	V
V_{CEO}	Collector-emitter voltage ($I_B = 0$)	-30	V
V_{EBO}	Emitter-base voltage ($I_C = 0$)	-5	V
I_C	Collector current	-3	A
I_{CM}	Collector peak current ($t_p < 5$ ms)	-6	A
I_B	Base current	-1	A
I_{BM}	Base peak current ($t_p < 5$ ms)	-2	A
P_{tot}	Total dissipation at $T_a = 25$ °C	0.9	W
T_{stg}	Storage temperature	-65 to 150	°C
T_J	Max. operating junction temperature	150	°C

Table 3. Thermal data

Symbol	Parameter	Value	Unit
$R_{thj-case}$	Thermal resistance junction-case max	44.6	°C/W
$R_{thj-amb}$	Thermal resistance junction-ambient max	139	°C/W

2 Electrical characteristics

($T_{\text{case}} = 25\text{ °C}$; unless otherwise specified)

Table 4. Electrical characteristics

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
I_{CES}	Collector cut-off current ($V_{\text{BE}} = 0$)	$V_{\text{CE}} = -60\text{ V}$			-10	μA
I_{CEO}	Collector cut-off current ($I_{\text{B}} = 0$)	$V_{\text{CE}} = -30\text{ V}$			-100	μA
I_{EBO}	Emitter cut-off current ($I_{\text{C}} = 0$)	$V_{\text{EB}} = -5\text{ V}$			-10	μA
$V_{(\text{BR})\text{CBO}}$	Collector-base breakdown voltage ($I_{\text{E}} = 0$)	$I_{\text{C}} = -100\text{ }\mu\text{A}$	-60			V
$V_{(\text{BR})\text{CEO}}^{(1)}$	Collector-emitter breakdown voltage ($I_{\text{B}} = 0$)	$I_{\text{C}} = -10\text{ mA}$	-30			V
$V_{(\text{BR})\text{EBO}}$	Emitter-base breakdown voltage ($I_{\text{C}} = 0$)	$I_{\text{E}} = -100\text{ }\mu\text{A}$	-5			V
$V_{\text{CE}(\text{sat})}^{(1)}$	Collector-emitter saturation voltage	$I_{\text{C}} = -1\text{ A}$ $I_{\text{B}} = -50\text{ mA}$ $I_{\text{C}} = -2\text{ A}$ $I_{\text{B}} = -100\text{ mA}$ $I_{\text{C}} = -3\text{ A}$ $I_{\text{B}} = -150\text{ mA}$			-0.4 -0.7 -1.1	V V V
$V_{\text{BE}(\text{sat})}^{(1)}$	Base-emitter saturation voltage	$I_{\text{C}} = -2\text{ A}$ $I_{\text{B}} = -100\text{ mA}$			-1.2	V
h_{FE}	DC current gain	$I_{\text{C}} = -100\text{ mA}$ $V_{\text{CE}} = -2\text{ V}$ $I_{\text{C}} = -1\text{ A}$ $V_{\text{CE}} = -2\text{ V}$ $I_{\text{C}} = -3\text{ A}$ $V_{\text{CE}} = -2\text{ V}$	100 80 30		300	
f_{T}	Transition frequency	$V_{\text{CE}} = -10\text{ V}$ $I_{\text{C}} = -0.1\text{ A}$		100		MHz

1. Pulse duration = 300 μs , duty cycle $\leq 1.5\%$

2.1 Electrical characteristics (curves)

Figure 2. DC current gain ($V_{CE}=2\text{ V}$)

Figure 3. DC Current Gain ($V_{CE}=5\text{ V}$)

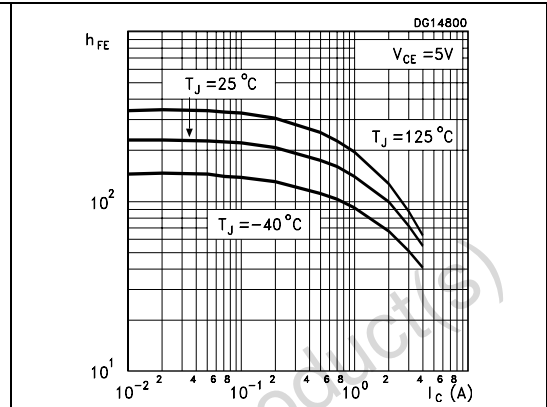
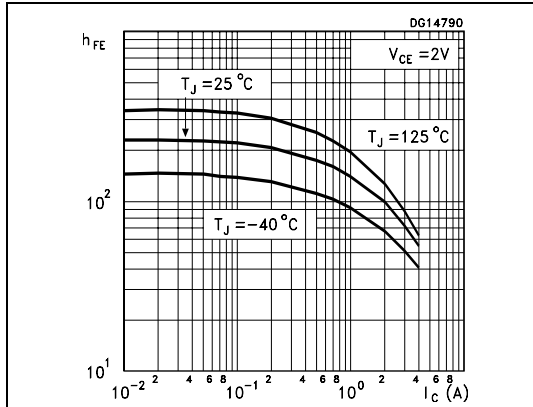


Figure 4. Collector-emitter saturation voltage

Figure 5. Base-emitter saturation voltage

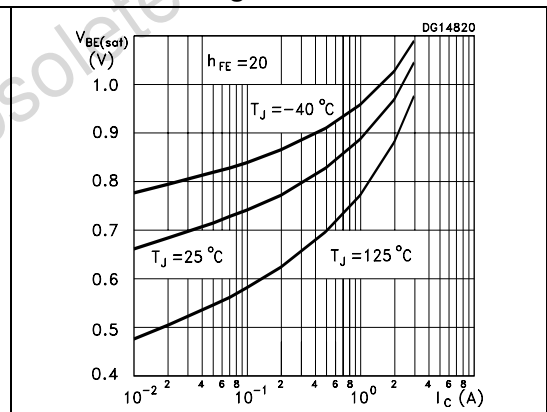
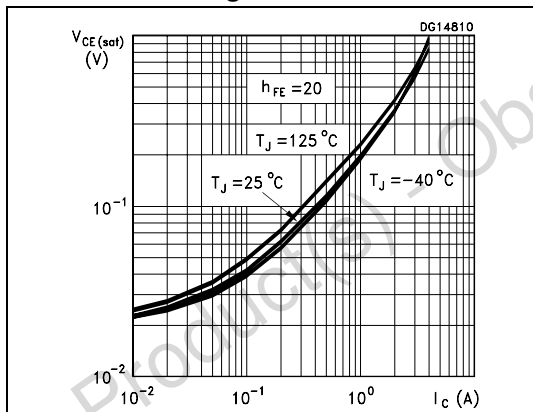


Figure 6. Resistive load switching time (OFF)

Figure 7. Resistive load switching time (ON)

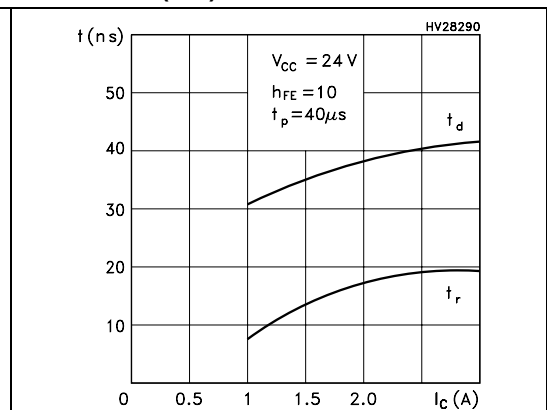
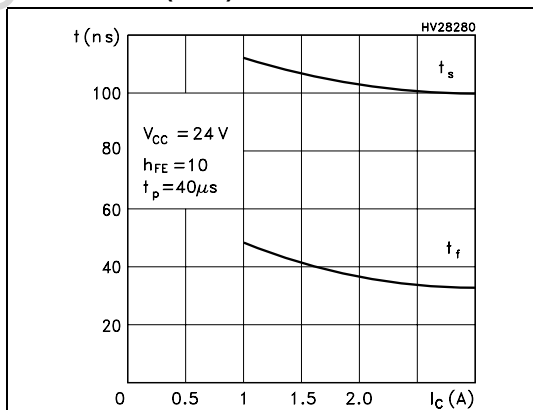
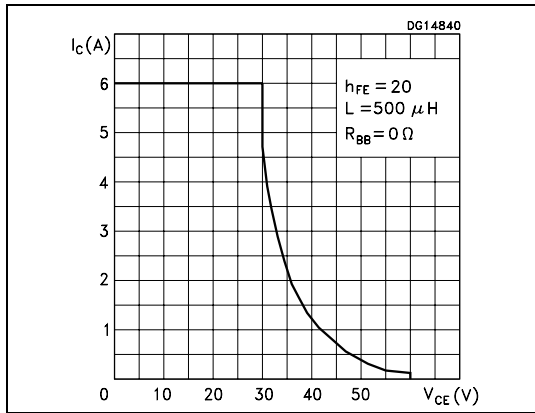


Figure 8. Reverse biased safe operating area

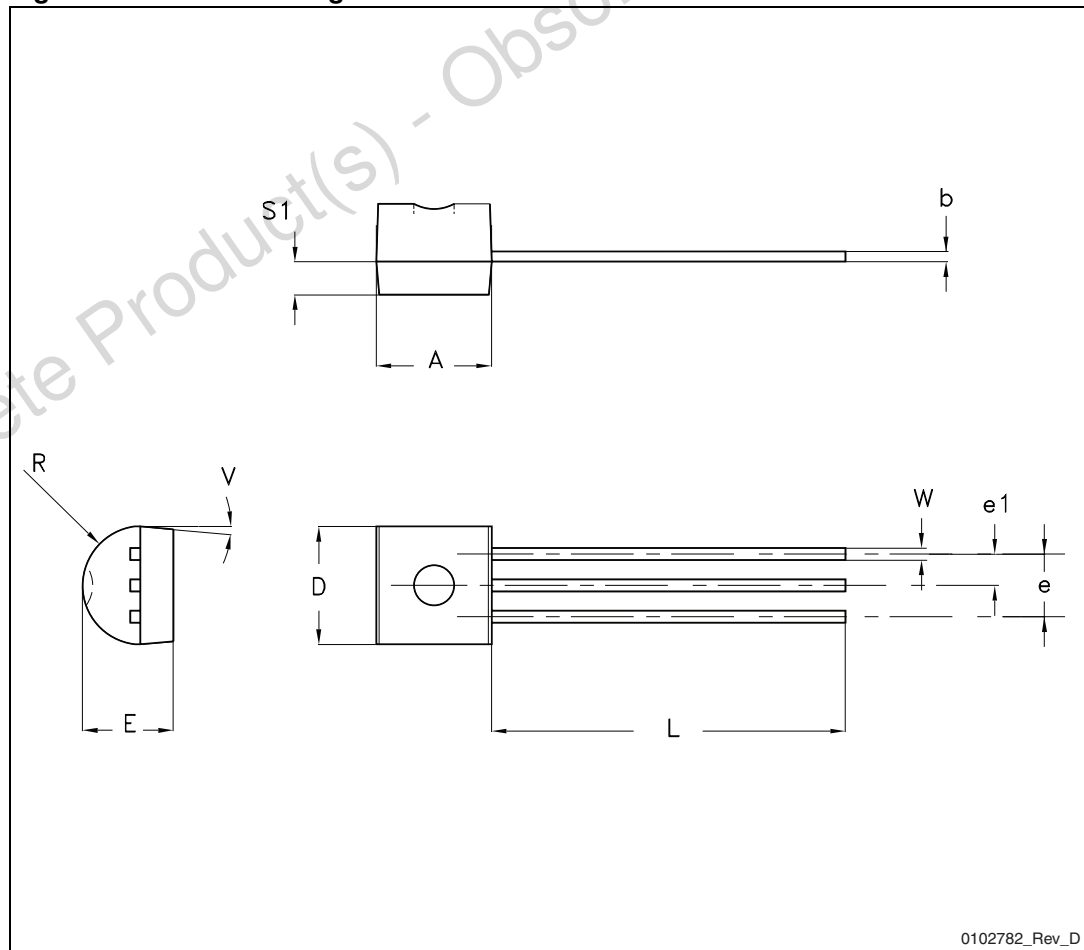


Obsolete Product(s) - Obsolete Product(s)

Table 5. TO-92 mechanical data

Dim.	mm		
	Min.	Typ.	Max.
A	4.32		4.95
b	0.36		0.51
D	4.45		4.95
E	3.30		3.94
e	2.41		2.67
e1	1.14		1.40
L	12.70		15.49
R	2.16		2.41
S1	0.92		1.52
W	0.41		0.56
V		5°	

Figure 9. TO-92 drawings



0102782_Rev_D

3 Package mechanical data

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Obsolete Product(s) - Obsolete Product(s)

4 Revision history

Table 6. Document revision history

Date	Revision	Changes
18-Oct-2005	2	Curves inserted
27-Apr-2011	3	Changed: Figure 1

Obsolete Product(s) - Obsolete Product(s)

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